

## PMP11180 REV A Bill of Materials

FCEI	Designator	Quantity	Value	PartNumber	Manufacturer	Description	PackageReference
C2		1					
C2, C3	C1	1	4700pF	DE2E3KY472MB3BM02F		CAP, CERM, 4700 pF, 250 V, +/- 20%, E, 10x5x13mm	10x5x13mm
C4, C5, C6         3         47UF         GRM31CR614A76RE15L         MuRetal         CAP, CERM, UP, 10V, ++ 10%, XSR, 1206         1206           C7, C10         2         1 UF         GRM115SR61A05KE15D         MuRetal         CAP, CERM, UP, 10V, ++ 10%, XSR, 1006         0402           C8         1         33UF         EEUED2D330         Panasonic         CAP, AL, 33UF, 200V, +/-20%, 0542873 ohm, TH         10x20           C11         1         2200pF         GRM15SR71E222K04D1         MuRetal         CAP, AL, 33UF, 200V, +/-20%, 0542873 ohm, TH         10x20           C12         1         100 C22µF         GRM15SR71E22X6A01D         MuRetal         CAP, CERM, 200 pF, 28V, +-4* 10%, XSR, 1402         0402           C13         1         0.022µF         GRM15SR71H20X6A02D         MuRetal         CAP, CERM, 200 pF, 28V, +-4* 10%, XSR, 1402         0402           C13         1         0.022µF         GRM15SR61E104KA67D         MuRetal         CAP, CERM, 0.01 pF, 28 V, +-10%, XSR, 0402         0402           C3.0         C3.0         4         0.10F         GRM15SR61E104KA67D         MuRetal         CAP, CERM, 0.1 pF, 28 V, +-10%, XSR, 0402         0402           C3.2         C4.0         C22, 2.7         3         0.01 uF         GRM15SR61E104KA67D         MuRetal         CAP, CERM, 0.1 p		2					
CR							
C8		2			MuRata		
1		1					
C11         1         2200pF         GRM156R71E22ZE(AD10         MuRata         CAP, CERM, 2200 pF, 25 V, 4-10%, X7R, 0402         0402           C13         1         0.022uF         GRM156R71H2ZSKR12D         MuRata         CAP, CERM, 0.00 pF, 25 V, 4-10%, X7R, 0402         0402           C14, C17, C18,         6         10uF         GRM2198614706Ke44D         MuRata         CAP, CERM, 0.02 pF, 50 V, 4-10%, XFR, 0402         0402           C18, C30, C31         CAP, CERM, 0.02 pF, 50 V, 4-10%, XFR, 0402         0402         0402           C33         CAP, CERM, 0.01 pF, 25 V, 4-10%, XFR, 0402         0402           C33         CAP, CERM, 0.01 pF, 25 V, 4-10%, XFR, 0402         0402           C32, C27, C28, C27, C28, C27, C28, C22, C29, C29, C29, C29, C29, C29, C29		1			Wurth Elektronik		18x6x11.5mm
C12		1					
C14. C17. C18. 6 1 0.022µF GRM/SSR71H223KA12D MURSIS CAP, CERM, 10 µF, 10 V. + 10%, X7R, 0402 0402 C14. C17. C18. 6 10µF GRM15R61A106KE44D MURSIS CAP, CERM, 10 µF, 10 V. + 10%, X5R, 0405 0305 C28. C30. C31 C31 C32. C21. 8 C32. C22. C27. C28. C28. C33 C33 C33 C33 C34. C35 C35 C35 C35 C36 C37 C37 C38 C37 C38 C38 C38 C38 C39		1					
C14. C17. C18.   6   10uF   GRM219R61A106KE44D   MuRata   CAP, CERM, 10 μF, 10 V, +/- 10%, X5R, 0805   0805	C13	1	0.022uF	GRM155R71H223KA12D	MuRata		
(28, 230, 231		6	1				
C15, C16, C25,   4							
C39         C20         C21, C20, C21, C28, C27, C28, C27, C28, C27, C28, C27, C28, C29         S2UF         GRM21BR60J226ME39L         MuRata         CAP, CERM, 22 μF, 6.3 V, +/- 20%, X5R, 0805         0805           C32, C24, C29         3         0.01 uF         GCM155R71E103KA37D         MuRata         CAP, CERM, 0.01 μF, 25 V, +/- 10%, X7R, 0402         0402           C32         1         33pF         GRM155SC1H330JA0TD         MURata         CAP, CERM, 0.01 μF, 25 V, +/- 10%, X7R, 0402         0402           C32         1         0.47 μF         GRM155SC1H330JA0TD         MURata         CAP, CERM, 0.01 μF, 25 V, +/- 10%, X7R, 0402         0402           D1         1         1 V         HD04-T         Diode, SMC100A         Littlefuse         Diode, SWitching-Bridge, 400V, 08A, MiniDIP         MiniDIP           D2         1         100V         MCM100A         Littlefuse         Diode, SWitching-Bridge, 400V, 08A, MiniDIP         MiniDIP           D3         1         1.05V         MURAT6073G         ON Semiconductor         Diode, Switching-Bridge, 400V, 08A, MiniDIP         SMC           D4         1         1.00V         MS316;115         NNP Semiconductor         Diode, Utrafast, 500V, 1A, SMA         SMA           D3         1         1.05V         MS416;415         NNP Semiconductor		4	0.1uF	GRM155R61E104KA87D	MuRata	CAP, CERM, 0.1 µF, 25 V, +/- 10%, X5R, 0402	0402
C19, C20, C21, C8, C22, C27, C28, C34, C28         8         22uF         GRM21BR60J226ME39L         MuRata         CAP, CERM, 22 μF, 63 V, 4/- 20%, X5R, 0805         0805           C22, C27, C28, C34, C29         3         0.01 uF         GCM155R71E103KA37D         MuRata         CAP, CERM, 0.01 μF, 25 V, 4/- 10%, X7R, 0402         0402           C32         1         339F         GRM155R61C474KE01         MuRata         CAP, CERM, 33 pF, 50 V, 4/- 5%, C0G/NP0, 0402         0402           C36         1         0.47uF         GRM155R61C474KE01         MuRata         CAP, CERM, 047 μF, 16 V, 4/- 10%, X5R, 0402         0402           D1         1         1V         HD04-T         Diodes Inc.         Diodes, Switching-Bridge, 400V, 0.8A, MinDIP         MinDIDP           D2         1         100V         SMCJ100A         Littefluse         Diode, TVS, Uni, 100 V, 1500 W, SMC         SMC           D3         1         1,105V         MuRA160T3G         ON Semiconductor         Diode, Utrafast, 600V, 0.25A, SOD-323         SOD-323           D4         1         100V         BAS316,115         NXP Semiconductor         Diode, Utrafast, 100V, 0.25A, SOT-523         SOT-623           F1         1         30V         BAT545T-7-F         Diodes Inc.         Diode, Schottky, 30 V, 0.2 A, SOT-523         SOT-623							
C22, C27, C28, C23, C24, C29   3		8	22uF	GRM21BR60J226ME39L	MuRata	CAP, CERM, 22 µF, 6.3 V, +/- 20%, X5R, 0805	0805
C34, C35         CAP, CERM, 0.01 µF, 25 V, 4/- 10%, X7R, 0402         0402           C32, C24, C29         3         0.01 µF, 25 V, 4/- 10%, X7R, 0402         0402           C32         1         33pF         GRM155S5C1H330JA01D         MuRata         CAP, CERM, 33 pF, 50 V, 4/- 10%, X5R, 0402         0402           C36         1         0.47µF         GRM155R61C474KE01         MuRata         CAP, CERM, 33 pF, 50 V, 4/- 10%, X5R, 0402         0402           D1         1         1 V         HD04-T         Diodes Inc.         Diode, Switching-Bridge, 400V, 03A, MinIDIP         MinIDIP           D2         1         100V         SMCJ100A         Littefluse         Diode, Switching-Bridge, 400V, 03A, MinIDIP         MinIDIP           D3         1         1.05V         MURA16073G         ON Semiconductor         Diode, Ultrafast, 600V, 1A, SMA         SMC           D4         1         1.00V         BAS316,115         NXP Semiconductor         Diode, Ultrafast, 100V, 0.25A, SOD-323         SOD-323           D5         1         3.0V         BAT64ST-7F         Diodes Inc.         Diodes Inc.         Diodes, Ditty, 34, MA           J1         1         0.452003.         Littefluse         Fuse, 3A, 125V, SMD         SIGBI0452           F1         1         1							
C23, C24, C29         3         0.01 μF         GCM155R71E1030AA0TD         MuRata         CAP, CERM, 0.01 μF, 25 V, +/- 10%, X7R, 0.402         0.402           C32         1         3.3pF         GRM1555C141330JA01D         MuRata         CAP, CERM, 0.3 pF, 50 V, +/- 5%, COG/NPO, 0402         0.402           C36         1         0.47uF         GRM155R61C474KE01         MuRata         CAP, CERM, 0.47 μF, 16 V, +/- 10%, X5R, 0402         0.402           D1         1         1V         HD04-T         Diodes Inc.         Diode, NS, Uni, 100 V, 1500 W, SMC         SMC           D3         1         1.05V         MURA160T3G         ON Semiconductor         Diode, Ultrafast, 600V, 1A, SMA         SMA           D4         1         1.09V         BAS316,115         NXP Semiconductor         Diode, Ultrafast, 100V, 0.25A, SOD-323         SOD-323           D5         1         30V         BAT54ST-7-F         Diodes Inc.         Diode, Schottky, 30 V, 0.2 A, SOT-623         SOT-523           F1         1         770W-X2/10         Qualtek Electronics Corporatel AC Receptacide, 2.5A, R/A, TH         AC, Reception 14.5sr(3x22 mm           L1         1         30 ohm         MPZ2012S300AT000         TDK         Ferrite Bead, 30 ohm @ 100 MHz, 6 A, 0805         0805           L2         1         <							
G32         1         33pF         GRM155SC1H330JA01D         MuRata         CAP, CERM, 32 pF, 50 V, 4+5%, COG/NPO, 0402         0402           C36         1         0.47uF         GRM155R51C474KE01         MuRata         CAP, CERM, 047 µF, 16 V, 4+10%, XSR, 0402         0402           D1         1         1V         HD04-T         Diode, Switching-Bridge, 400V, 0.8A, MinIDIP         MinIDIP           D2         1         100V         SMCJ100A         Littefluse         Diode, NVS, Uni, 100 V, 1500 W, SMC         SMC           D3         1         1.05V         MURAT60T3G         ON Semiconductor         Diode, Ultrafast, 600V, 1A, SMA         SMA           D4         1         100V         BAS316,115         NXP Semiconductor         Diode, Ultrafast, 600V, 1A, SMA         SMA           D5         1         30V         BAT54ST-7-F         Diodes Inc.         Diodes, Schottky, 30 V, 02 A, SOT-523         SOT-523         SOT-523           F1         1         0.452003.         Littefluse         Fuse, 3A, 125V, SMD         SloBio452           J1         1         770W-X2/10         Qualtek Electronics Corporatid AC Receptacle, 2,5A, R/A, TH         AC, Reception           L1         1         30 ohm         MP22012S300AT000         TDK         Ferrite Bead, 30 ohm		3	0.01uF	GCM155R71E103KA37D	MuRata	CAP, CERM, 0.01 µF, 25 V, +/- 10%, X7R, 0402	0402
C36		1	33pF	GRM1555C1H330JA01D			0402
D1		1		GRM155R61C474KE01	MuRata		0402
D2		1	1V	HD04-T	Diodes Inc.		MiniDIP
DA	D2	1					SMC
Diode   Diode   Diode   Chottky, 30 V, 0.2 A, SOT-523   SOT-523	D3	1	1.05V	MURA160T3G	ON Semiconductor	Diode, Ultrafast, 600V, 1A, SMA	SMA
F1	D4	1	100V	BAS316,115	NXP Semiconductor	Diode, Ultrafast, 100V, 0.25A, SOD-323	SOD-323
F1	D5	1	30V	BAT54ST-7-F	Diodes Inc.	Diode, Schottky, 30 V, 0.2 A, SOT-523	SOT-523
L1   1   30 ohm   MPZ2012S300AT000   TDK   Ferrite Bead, 30 ohm @ 100 MHz, 6 A, 0805   0805	F1	1		0452003.	Littelfuse		SloBlo452
L1   1   30 ohm   MPZ2012S300AT000   TDK   Ferrite Bead, 30 ohm @ 100 MHz, 6 A, 0805   0805	J1	1		770W-X2/10	Qualtek Electronics Corpora	atiqAC Receptacle, 2.5A, R/A, TH	AC, Reception
L2         1         10mH         744821110         Wurth Elektronik         Coupled inductor, 10 mH, 0.7 A, 0.35 ohm, +/- 30%, TH         15 x 18 x 7.5mm           L3, L6         2         1.5uH         XAL4020-152MEB         Coilcraft         Inductor, Shielded, Composite, 1.5 μH, 7.12 A, 0.02 ohm, SMD         4x2.1x4mm           L4, L5         2         2.2uH         XAL4020-222MEB         Coilcraft         Inductor, Shielded, Composite, 2.2 μH, 5.5 A, 0.04 ohm, SMD         4x2.1x4mm           Q1         1         30V         CSD17559Q5         Texas Instruments         MOSFET, N-CH, 30 V, 100 A, SON 5x6mm         SON 5x6mm         SON 5x6mm         SON 5x6mm         SON 5x6mm         DPAK           Q2         1         600V         AOD11S60         AOS         MOSFET, N-CH, 600 V, 11 A, DPAK         DPAK           R1         1         1.00k         CRCW04021K00FKED         Vishay-Dale         RES, 1.00k ohm, 1%, 0.063W, 0402         0402           R2         1         221k         CRCW040222KFKED         Vishay-Dale         RES, 21 k, 1%, 0.063 W, 0402         0402           R3         1         51         CRCW040221KFKED         Vishay-Dale         RES, 51, 5%, 0.25 W, 1206         1206           R4         1         150k         CRCW04022NKFKED         Vishay-Dale         RE							
C3, L6   2   1.5 \text{UH}	L1	1	30 ohm	MPZ2012S300AT000	TDK	Ferrite Bead, 30 ohm @ 100 MHz, 6 A, 0805	0805
L4, L5         2         2.2 μH         XAL4020-222MEB         Coilcraft         Inductor, Shielded, Composite, 2.2 μH, 5.5 A, 0.04 ohm, SMD         4x2.1x4mm           Q1         1         30V         CSD17559Q5         Texas Instruments         MOSFET, N-CH, 30 V, 100 A, SON 5x6mm         SON 5x6mm           Q2         1         600V         AOD11S60         AOS         MOSFET, N-CH, 600 V, 11 A, DPAK         DPAK           R1         1         1.00k         CRCW04021K00FKED         Vishay-Dale         RES, 1.00k ohm, 1%, 0.063W, 0402         0402           R2         1         221k         CRCW0402221KFKED         Vishay-Dale         RES, 221 k, 1%, 0.063 W, 0402         0402           R3         1         51         CRCW120651R0JNEA         Vishay-Dale         RES, 51, 5%, 0.25 W, 1206         1206           R4         1         150k         CRCW0402150KFKED         Vishay-Dale         RES, 150 k, 1%, 0.063 W, 0402         0402           R5         1         4.7         CRCW12064R70JNEA         Vishay-Dale         RES, 4.7, 5%, 0.25 W, 1206         1206           R20, R23, R24, R29, R30, R31, R34, R35         1         10.0k         CRCW0402210K0FKED         Vishay-Dale         RES, 37.4 k, 1%, 0.063 W, 0402         0402           R8         1         20	L2	1	10mH	744821110	Wurth Elektronik	Coupled inductor, 10 mH, 0.7 A, 0.35 ohm, +/- 30%, TH	15 x 18 x 7.5mm
Q1         1         30V         CSD17559Q5         Texas Instruments         MOSFET, N-CH, 30 V, 100 A, SON 5x6mm         SON 5x6mm           Q2         1         600V         AOD11S60         AOS         MOSFET, N-CH, 600 V, 11 A, DPAK         DPAK           R1         1         1.00k         CRCW04021K0FKED         Vishay-Dale         RES, 1.00k ohm, 1%, 0.063W, 0402         0402           R2         1         221k         CRCW0402221KFKED         Vishay-Dale         RES, 221 k, 1%, 0.063 W, 0402         0402           R3         1         51         CRCW120651R0JNEA         Vishay-Dale         RES, 51, 5%, 0.25 W, 1206         1206           R4         1         150k         CRCW0402150KFKED         Vishay-Dale         RES, 150 k, 1%, 0.063 W, 0402         0402           R5         1         4.7         CRCW12064R70JNEA         Vishay-Dale         RES, 4.7, 5%, 0.25 W, 1206         1206           R6, R13, R18, R18, R20, R23, R24, R29, R30, R31, R34, R35         1         1         10.0k         CRCW040210K0FKED         Vishay-Dale         RES, 37.4 k, 1%, 0.063 W, 0402         0402           R8         1         20         CRCW040220R0JNED         Vishay-Dale         RES, 20, 5%, 0.063 W, 0402         0402           R9         1         20.0k		2	1.5uH	XAL4020-152MEB	Coilcraft	Inductor, Shielded, Composite, 1.5 µH, 7.12 A, 0.02 ohm, SMD	4x2.1x4mm
Q2         1         600V         AOD11S60         AOS         MOSFET, N-CH, 600 V, 11 A, DPAK         DPAK           R1         1         1.00k         CRCW04021K00FKED         Vishay-Dale         RES, 1.00k ohm, 1%, 0.063W, 0402         0402           R2         1         221k         CRCW0402221KFKED         Vishay-Dale         RES, 221 k, 1%, 0.063 W, 0402         0402           R3         1         51         CRCW120651R0JNEA         Vishay-Dale         RES, 51, 5%, 0.25 W, 1206         1206           R4         1         150k         CRCW0402150KFKED         Vishay-Dale         RES, 150 k, 1%, 0.063 W, 0402         0402           R5         1         4.7         CRCW12064R70JNEA         Vishay-Dale         RES, 4.7, 5%, 0.25 W, 1206         1206           R6, R13, R18,         11         10.0k         CRCW040210K0FKED         Vishay-Dale         RES, 10.0 k, 1%, 0.063 W, 0402         0402           R20, R23, R24,         R29, R30, R31,         R34, R35         R24         R29, R30, R31,         R25, 10.0 k, 1%, 0.063 W, 0402         0402           R8         1         20         CRCW040220K0FKED         Vishay-Dale         RES, 20, 5%, 0.063 W, 0402         0402           R9         1         20.0k         CRCW040220K0FKED         Vishay-Dal	L4, L5	2	2.2uH	XAL4020-222MEB	Coilcraft	Inductor, Shielded, Composite, 2.2 µH, 5.5 A, 0.04 ohm, SMD	4x2.1x4mm
R1         1         1.00k         CRCW04021K00FKED         Vishay-Dale         RES, 1.00k ohm, 1%, 0.063W, 0402         0402           R2         1         221k         CRCW0402221KFKED         Vishay-Dale         RES, 221 k, 1%, 0.063 W, 0402         0402           R3         1         51         CRCW120651R0JNEA         Vishay-Dale         RES, 51, 5%, 0.25 W, 1206         1206           R4         1         150k         CRCW0402150KFKED         Vishay-Dale         RES, 150 k, 1%, 0.063 W, 0402         0402           R5         1         4.7         CRCW12064R70JNEA         Vishay-Dale         RES, 4.7, 5%, 0.25 W, 1206         1206           R6, R13, R18, R29, R30, R31, R29, R30, R31, R34, R35         1         10.0k         CRCW040210K0FKED         Vishay-Dale         RES, 10.0 k, 1%, 0.063 W, 0402         0402           R7         1         37.4k         CRCW040220R0JNED         Vishay-Dale         RES, 37.4 k, 1%, 0.063 W, 0402         0402           R8         1         20         CRCW040220R0JNED         Vishay-Dale         RES, 20, 5%, 0.063 W, 0402         0402           R9         1         20.0k         CRCW040220K0FKED         Vishay-Dale         RES, 20.0 k, 1%, 0.063 W, 0402         0402	Q1	1	30V	CSD17559Q5	Texas Instruments	MOSFET, N-CH, 30 V, 100 A, SON 5x6mm	SON 5x6mm
R2         1         221k         CRCW0402221KFKED         Vishay-Dale         RES, 221 k, 1%, 0.063 W, 0402         0402           R3         1         51         CRCW120651R0JNEA         Vishay-Dale         RES, 51, 5%, 0.25 W, 1206         1206           R4         1         150k         CRCW0402150KFKED         Vishay-Dale         RES, 150 k, 1%, 0.063 W, 0402         0402           R5         1         4.7         CRCW12064R70JNEA         Vishay-Dale         RES, 4.7, 5%, 0.25 W, 1206         1206           R6, R13, R18, R20, R31, R20, R321, R29, R30, R31, R34, R35         1         10.0k         CRCW040210K0FKED         Vishay-Dale         RES, 10.0 k, 1%, 0.063 W, 0402         0402           R7         1         37.4k         CRCW040237K4FKED         Vishay-Dale         RES, 37.4 k, 1%, 0.063 W, 0402         0402           R8         1         20         CRCW040220R0JNED         Vishay-Dale         RES, 20, 5%, 0.063 W, 0402         0402           R9         1         20.0k         CRCW040220K0FKED         Vishay-Dale         RES, 20.0 k, 1%, 0.063 W, 0402         0402	Q2	1	600V	AOD11S60	AOS	MOSFET, N-CH, 600 V, 11 A, DPAK	DPAK
R3         1         51         CRCW120651R0JNEA         Vishay-Dale         RES, 51, 5%, 0.25 W, 1206         1206           R4         1         150k         CRCW0402150KFKED         Vishay-Dale         RES, 150 k, 1%, 0.063 W, 0402         0402           R5         1         4.7         CRCW12064R70JNEA         Vishay-Dale         RES, 4.7, 5%, 0.25 W, 1206         1206           R6, R13, R18, R29, R30, R31, R34, R35         11         10.0k         CRCW040210K0FKED         Vishay-Dale         RES, 10.0 k, 1%, 0.063 W, 0402         0402           R7         1         37.4k         CRCW040227K4FKED         Vishay-Dale         RES, 37.4 k, 1%, 0.063 W, 0402         0402           R8         1         20         CRCW040220R0JNED         Vishay-Dale         RES, 20, 5%, 0.063 W, 0402         0402           R9         1         20.0k         CRCW040220K0FKED         Vishay-Dale         RES, 20.0 k, 1%, 0.063 W, 0402         0402	R1	1			Vishay-Dale	RES, 1.00k ohm, 1%, 0.063W, 0402	
R4         1         150k         CRCW0402150KFKED         Vishay-Dale         RES, 150 k, 1%, 0.063 W, 0402         0402           R5         1         4.7         CRCW12064R70JNEA         Vishay-Dale         RES, 4.7, 5%, 0.25 W, 1206         1206           R6, R13, R18, R24, R29, R30, R31, R34, R35         1         10.0k         CRCW040237K4FKED         Vishay-Dale         RES, 10.0 k, 1%, 0.063 W, 0402         0402           R7         1         37.4k         CRCW040227K4FKED         Vishay-Dale         RES, 37.4 k, 1%, 0.063 W, 0402         0402           R8         1         20         CRCW040220R0JNED         Vishay-Dale         RES, 20, 5%, 0.063 W, 0402         0402           R9         1         20.0k         CRCW040220K0FKED         Vishay-Dale         RES, 20.0 k, 1%, 0.063 W, 0402         0402		1					
R5         1         4.7         CRCW12064R70JNEA         Vishay-Dale         RES, 4.7, 5%, 0.25 W, 1206         1206           R6, R13, R18, R24, R29, R30, R31, R34, R35         11         10.0k         CRCW040210K0FKED         Vishay-Dale         RES, 10.0 k, 1%, 0.063 W, 0402         0402           R7         1         37.4k         CRCW040237K4FKED         Vishay-Dale         RES, 37.4 k, 1%, 0.063 W, 0402         0402           R8         1         20         CRCW040220R0JNED         Vishay-Dale         RES, 20, 5%, 0.063 W, 0402         0402           R9         1         20.0k         CRCW040220K0FKED         Vishay-Dale         RES, 20.0 k, 1%, 0.063 W, 0402         0402		1		CRCW120651R0JNEA	Vishay-Dale	RES, 51, 5%, 0.25 W, 1206	
R6, R13, R18,       11       10.0k       CRCW040210K0FKED       Vishay-Dale       RES, 10.0 k, 1%, 0.063 W, 0402       0402         R20, R23, R24,       R29, R30, R31,       R34, R35       R24, R35       R24, R35       R25, 37.4 k, 1%, 0.063 W, 0402       0402         R8       1       20       CRCW040220R0JNED       Vishay-Dale       RES, 20, 5%, 0.063 W, 0402       0402         R9       1       20.0k       CRCW040220K0FKED       Vishay-Dale       RES, 20.0 k, 1%, 0.063 W, 0402       0402		1		CRCW0402150KFKED	Vishay-Dale	RES, 150 k, 1%, 0.063 W, 0402	0402
R20, R23, R24,       R29, R30, R31,       R34, R35       R34, R35       R5, 37.4 k, 1%, 0.063 W, 0402       0402         R7       1       37.4k       CRCW040237K4FKED       Vishay-Dale       RES, 37.4 k, 1%, 0.063 W, 0402       0402         R8       1       20       CRCW040220R0JNED       Vishay-Dale       RES, 20, 5%, 0.063 W, 0402       0402         R9       1       20.0k       CRCW040220K0FKED       Vishay-Dale       RES, 20.0 k, 1%, 0.063 W, 0402       0402		1	4.7	CRCW12064R70JNEA		RES, 4.7, 5%, 0.25 W, 1206	
R29, R30, R31,       R34, R35       R34, R35       R35       R5       R5       R5, 37.4 k, 1%, 0.063 W, 0402       R6       R5, 37.4 k, 1%, 0.063 W, 0402       R6       R5, 37.4 k, 1%, 0.063 W, 0402       R6       R		11	10.0k	CRCW040210K0FKED	Vishay-Dale	RES, 10.0 k, 1%, 0.063 W, 0402	0402
R34, R35         R34, R35         R37.4k         CRCW040237K4FKED         Vishay-Dale         RES, 37.4 k, 1%, 0.063 W, 0402         0402           R8         1         20         CRCW040220R0JNED         Vishay-Dale         RES, 20, 5%, 0.063 W, 0402         0402           R9         1         20.0k         CRCW040220K0FKED         Vishay-Dale         RES, 20.0 k, 1%, 0.063 W, 0402         0402							
R7         1         37.4k         CRCW040237K4FKED         Vishay-Dale         RES, 37.4 k, 1%, 0.063 W, 0402         0402           R8         1         20         CRCW040220R0JNED         Vishay-Dale         RES, 20, 5%, 0.063 W, 0402         0402           R9         1         20.0k         CRCW040220K0FKED         Vishay-Dale         RES, 20.0 k, 1%, 0.063 W, 0402         0402							
R8         1         20         CRCW040220R0JNED         Vishay-Dale         RES, 20, 5%, 0.063 W, 0402         0402           R9         1         20.0k         CRCW040220K0FKED         Vishay-Dale         RES, 20.0 k, 1%, 0.063 W, 0402         0402							
R9 1 20.0k CRCW040220K0FKED Vishay-Dale RES, 20.0 k, 1%, 0.063 W, 0402 0402							
		<u>'</u>					
R10   1   90.9k   CRCW040290K9FKED   Vishay-Dale   RES, 90.9 k, 1%, 0.063 W, 0402   0402							
	R10	1	90.9k	CRCW040290K9FKED	Vishay-Dale	RES, 90.9 k, 1%, 0.063 W, 0402	0402

Designator	Quantity	Value	PartNumber	Manufacturer	Description	PackageReference
R11	1	1.78k	CRCW04021K78FKED	Vishay-Dale	RES, 1.78 k, 1%, 0.063 W, 0402	0402
R12	1	24.9k	CRCW040224K9FKED	Vishay-Dale	RES, 24.9 k, 1%, 0.063 W, 0402	0402
R14	1	0.43	MCR18EZHJLR43	Rohm	RES, 0.43, 5%, 0.25 W, 1206	1206
R15	1	0	CRCW04020000Z0ED	Vishay-Dale	RES, 0, 5%, 0.063 W, 0402	0402
R16	1	499	CRCW0402499RFKED	Vishay-Dale	RES, 499, 1%, 0.063 W, 0402	0402
R17	1	4.99k	CRCW04024K99FKED	Vishay-Dale	RES, 4.99 k, 1%, 0.063 W, 0402	0402
R19	1	30.1k	CRCW040230K1FKED	Vishay-Dale	RES, 30.1 k, 1%, 0.063 W, 0402	0402
R21	1	3.32k	CRCW04023K32FKED	Vishay-Dale	RES, 3.32 k, 1%, 0.063 W, 0402	0402
R22, R25, R26, R32, R38	5	100k	CRCW0402100KFKED	Vishay-Dale	RES, 100 k, 1%, 0.063 W, 0402	0402
R27. R36	2	33.2k	CRCW040233K2FKED	Vishay-Dale	RES, 33.2 k, 1%, 0.063 W, 0402	0402
R28	1	9.53k	CRCW04029K53FKED	Vishay-Dale	RES, 9.53 k, 1%, 0.063 W, 0402	0402
R33	1	22.6k	CRCW040222K6FKED	Vishay-Dale	RES, 22.6 k, 1%, 0.063 W, 0402	0402
R37	1	49.9k	CRCW040249K9FKED	Vishay-Dale	RES, 49.9 k, 1%, 0.063 W, 0402	0402
T1	1	220 uH	RLTI-1157	Renco Electronics	Transformer, 220 uH, TH	1100x890mil
TP1, TP3, TP4, TP9, TP12	5	Red	5010	Keystone	Test Point, Multipurpose, Red, TH	Red Multipurpose Testpoint
TP2, TP7, TP8, TP11, TP14	5	Black	5011	Keystone	Test Point, Multipurpose, Black, TH	Black Multipurpose Testpoint
TP5, TP6, TP10, TP13	4	Red	5000	Keystone	Test Point, Miniature, Red, TH	Red Miniature Testpoint
U1	1		UCC24636DBVR	Texas Instruments	SYNCRONOUS RECTIFIER CONTROLLER WITH LOW POWER STANDBY, DBV0006A	DBV0006A
U2	1		UCC28740DR	Texas Instruments	Constant-Voltage, Constant-Current Flyback Controller Using Opto- Coupler Feedback, D0007A	D0007A
U3	1		VOS617A-7X001T	Vishay-Semiconductor	OptoCoupler, Phototransitor, 80-160%, SSOP-4	7x2.12x2.6mm
U4	1		TLVH431AQDBVRQ1	Texas Instruments	LOW-VOLTAGE ADJUSTABLE PRECISION SHUNT REGULATOR, DBV0005A	DBV0005A
U5, U7	2		TPS562210DDF	Texas Instruments	TPS553210DDF, DDF0008A	DDF0008A
U6	1		TPS563210DDF	Texas Instruments	TPS553210DDF, DDF0008A	DDF0008A
U8	1		TPS56528DDA	Texas Instruments		DDA0008E

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